## Improved quasiparticle thermalization for single-electron turnstiles

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To advance towards metrologically useful current quantization accuracy in a turnstile based on a singleelectron transistor with superconducting aluminium electrodes and a normal metallic island, low density of both residual and drive-induced quasiparticles in the superconducting leads is required. I present results from recent measurements where the quasiparticle density at the turnstile junctions is actively lowered by an on-chip, tunnel junction-based electronic refrigerator. I further discuss experiments where the thickness of the Al electrodes has been increased by an order of magnitude compared to the maximum allowed by the standard fabrication process.